Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies; or wherever half-wave silicon gate-controlled, solid-state devices are needed.

Features

- Glass-Passivated Junctions
- Blocking Voltage to 400 Volts
- TO-220 Construction Low Thermal Resistance, High Heat Dissipation and Durability
- Pb-Free Packages are Available*

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (T _J = -40 to 125°C, Gate Open) MCR218-2 MCR218-4 MCR218-6	V _{DRM} , V _{RRM}	50 200 400	V
On-State RMS Current (180° Conduction Angles; T _C = 70°C)	I _{T(RMS)}	8.0	Α
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	I _{TSM}	100	Α
Circuit Fusing Considerations (t = 8.3 ms)	l ² t	26	A ² s
Forward Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 70°C)	P _{GM}	5.0	W
Forward Average Gate Power (t = 8.3 ms, T _C = 70°C)	P _{G(AV)}	0.5	W
Forward Peak Gate Current (Pulse Width \leq 1.0 μ s, T _C = 70°C)	I _{GM}	2.0	Α
Operating Junction Temperature Range	T _J	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

 V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



ON Semiconductor®

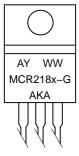
http://onsemi.com

SCRs 8 AMPERES RMS 50 thru 400 VOLTS









A = Assembly Location

ORDERING INFORMATION

Device	Package	Shipping
MCR218-2	TO220AB	500 Units/Bulk
MCR218-2G	TO220AB (Pb-Free)	500 Units/Bulk
MCR218-4	TO220AB	500 Units/Bulk
MCR218-4G	TO220AB (Pb-Free)	500 Units/Bulk
MCR218-6	TO220AB	500 Units/Bulk
MCR218-6G	TO220AB (Pb-Free)	500 Units/Bulk

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	2.0	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T_L	260	°C

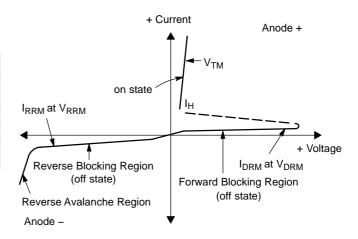
ELECTRICAL CHARACTERISTICS ($T_J = 25$ °C unless otherwise noted.)

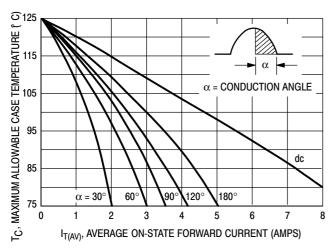
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•	•	
Peak Repetitive Forward or Reverse Blocking Current $(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, \text{ Gate Open})$ $T_J = 25^{\circ}\text{C}$	I _{DRM} , I _{RRM}	_	_	10	μΑ
T _J = 125°C		_	_	2.0	mA
ON CHARACTERISTICS					
Peak Forward On-State Voltage (Note 2) (I _{TM} = 16 A Peak)	V _{TM}	-	1.5	1.8	V
Gate Trigger Current (Continuous dc) $(V_D = 12 \text{ V}, R_L = 100 \text{ Ohms})$	I _{GT}	-	10	25	mA
Gate Trigger Voltage (Continuous dc) (V _D = 12 V, R _L = 100 Ohms)	V _{GT}	-	-	1.5	V
Gate Non–Trigger Voltage (Rated 12 V, R _L = 100 Ohms, T _J = 125°C)	$V_{\sf GD}$	0.2	-	-	V
Holding Current (V _D = 12 Vdc, Initiating Current = 200 mA, Gate Open)	H	-	16	30	mA
DYNAMIC CHARACTERISTICS		•			
Critical Rate-of-Rise of Off-State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, Gate Open, T _J = 125°C)	dv/dt	-	100	_	V/μs

^{2.} Pulse Test: Pulse Width = 1.0 ms, Duty Cycle ≤ 2%.

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Off State Forward Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Off State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Peak On State Voltage
I _H	Holding Current

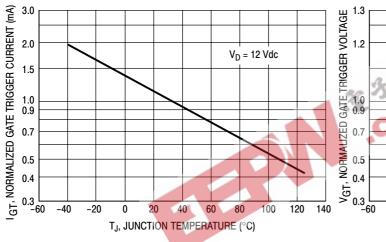




P(AV), AVERAGE ON-STATE POWER DISSIPATION (WATTS) 0 0 0 51 α dc α = Conduction Angle 180° 120° 60° $\alpha = 30^{\circ}$ 0 1.0 2.0 5.0 6.0 7.0 8.0 $I_{T(AV)}$, AVG. ON-STATE CURRENT (AMPS)

Figure 1. Current Derating

Figure 2. On-State Power Dissipation



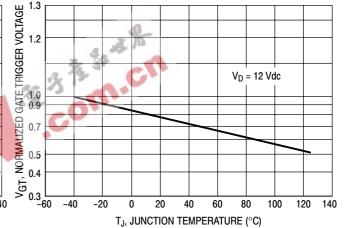


Figure 3. Typical Gate Trigger Current versus Temperature

Figure 4. Typical Gate Trigger Voltage versus Temperature

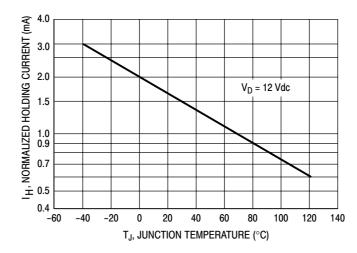
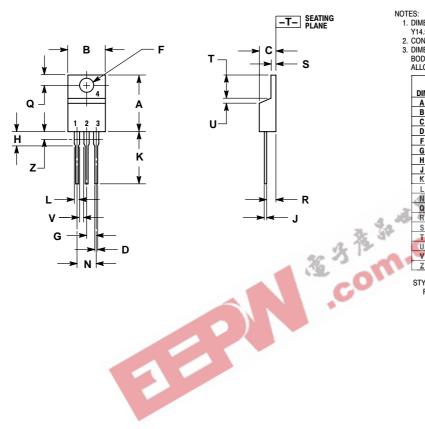


Figure 5. Typical Holding Current versus Temperature

PACKAGE DIMENSIONS

TO-220AB CASE 221A-07 **ISSUE AA**

-T- SEATING



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL
 BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Z		0.080		2.04

STYLE 3:

- CATHODE
 - ANODE 2.
 - GATE
 - ANODE

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